Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1905	(430/1 or 430/2 or 359/3 or 359/12). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:32
L2	38	I1 and (pdlc or ((polymer near5 dispersed) near5 (lc or crystal\$1)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:34
L3	5	(copy or copying or copied or (contact near5 expos\$6)) and I2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:35

```
$%^STN;HighlightOn= ***;HighlightOff=***
Connecting via Winsock to STN
Welcome to STN International! Enter x:x
LOGINID:ssspta1756mja
PASSWORD:
TERMINAL (ENTER 1, 2, 3, OR ?):2
                     Welcome to STN International
 NEWS
      1
                 Web Page URLs for STN Seminar Schedule - N. America
 NEWS
                  "Ask CAS" for self-help around the clock
 NEWS
     3 FEB 28
                 PATDPAFULL - New display fields provide for legal status
                 data from INPADOC
 NEWS
      4 FEB 28 BABS - Current-awareness alerts (SDIs) available
 NEWS 5 MAR 02 GBFULL: New full-text patent database on STN
 NEWS 6 MAR 03 REGISTRY/ZREGISTRY - Sequence annotations enhanced
 NEWS 7 MAR 03 MEDLINE file segment of TOXCENTER reloaded
 NEWS 8 MAR 22 KOREAPAT now updated monthly; patent information enhanced
 NEWS 9 MAR 22 Original IDE display format returns to REGISTRY/ZREGISTRY
 NEWS
     10 MAR 22 PATDPASPC - New patent database available
     11 MAR 22 REGISTRY/ZREGISTRY enhanced with experimental property tags
 NEWS
 NEWS
     12 APR 04 EPFULL enhanced with additional patent information and new
                 fields
      13 APR 04
                 EMBASE - Database reloaded and enhanced
NEWS
NEWS
      14 APR 18
                 New CAS Information Use Policies available online
 NEWS
      15 APR 25
                 Patent searching, including current-awareness alerts (SDIs),
                 based on application date in CA/CAplus and USPATFULL/USPAT2
                 applications.
NEWS
      16 APR 28
                 U.S. patent records in CA/CAplus
NEWS
      17 MAY 23
NEWS
      18 MAY 23
                 CHEMCATS
NEWS
      19 JUN 06
                  (Version 8.0 for Windows) now available
```

```
may be affected by a change in filing date for U.S.
                 Improved searching of U.S. Patent Classifications for
                 GBFULL enhanced with patent drawing images
                 REGISTRY has been enhanced with source information from
                 The Analysis Edition of STN Express with Discover!
NEWS
      20 JUN 13
                RUSSIAPAT: New full-text patent database on STN
NEWS
      21 JUN 13
                FRFULL enhanced with patent drawing images
                MARPAT displays enhanced with expanded G-group definitions
NEWS
     22 JUN 27
                 and text labels
                MEDICONF removed from STN
NEWS
     23 JUL 01
                 STN Patent Forums to be held in July 2005
NEWS
      24 JUL 07
NEWS
     25 JUL 13
                 SCISEARCH reloaded
                 Powerful new interactive analysis and visualization software,
NEWS
     26 JUL 20
```

Derwent World Patents Index(R) web-based training during

STN AnaVist workshops to be held in North America

NEWS EXPRESS JUNE 13 CURRENT WINDOWS VERSION IS V8.0, CURRENT MACINTOSH VERSION IS V6.0c(ENG) AND V6.0Jc(JP), AND CURRENT DISCOVER FILE IS DATED 13 JUNE 2005

STN AnaVist, now available

NEWS

NEWS

27 AUG 11

28 AUG 11

August

NEWS HOURS STN Operating Hours Plus Help Desk Availability NEWS INTER General Internet Information NEWS LOGIN Welcome Banner and News Items Direct Dial and Telecommunication Network Access to STN NEWS PHONE NEWS WWW CAS World Wide Web Site (general information)

Enter NEWS followed by the item number or name to see news on that specific topic.

All use of STN is subject to the provisions of the STN Customer agreement. Please note that this agreement limits use to scientific research. Use for software development or design or implementation of commercial gateways or other similar uses is prohibited and may result in loss of user privileges and other penalties.

FILE 'HOME' ENTERED AT 15:39:55 ON 16 AUG 2005

=> file caplus
COST IN U.S. DOLLARS

SINCE FILE TOTAL ENTRY SESSION 0.21 0.21

FULL ESTIMATED COST

FILE 'CAPLUS' ENTERED AT 15:40:03 ON 16 AUG 2005
USE IS SUBJECT TO THE TERMS OF YOUR STN CUSTOMER AGREEMENT.
PLEASE SEE "HELP USAGETERMS" FOR DETAILS.
COPYRIGHT (C) 2005 AMERICAN CHEMICAL SOCIETY (ACS)

Copyright of the articles to which records in this database refer is held by the publishers listed in the PUBLISHER (PB) field (available for records published or updated in Chemical Abstracts after December 26, 1996), unless otherwise indicated in the original publications. The CA Lexicon is the copyrighted intellectual property of the American Chemical Society and is provided to assist you in searching databases on STN. Any dissemination, distribution, copying, or storing of this information, without the prior written consent of CAS, is strictly prohibited.

FILE COVERS 1907 - 16 Aug 2005 VOL 143 ISS 8 FILE LAST UPDATED: 15 Aug 2005 (20050815/ED)

New CAS Information Use Policies, enter HELP USAGETERMS for details.

This file contains CAS Registry Numbers for easy and accurate substance identification.

```
(pdlc or ((polymer(4a)dispers?)(5a)(lc or lcd or (liquid(4a)crystal))))
      819 PDLC
      169 PDLCS
      884 PDLC
            (PDLC OR PDLCS)
  1020028 POLYMER
   840995 POLYMERS
  1381077 POLYMER
            (POLYMER OR POLYMERS)
   604841 DISPERS?
    32805 LC
     1228 LCS
    33413 LC
            (LC OR LCS)
    11200.LCD
     1147 LCDS
    11697 LCD
            (LCD OR LCDS)
   691088 LIQUID
   123676 LIQUIDS
   784645 LIQUID
            (LIQUID OR LIQUIDS)
   964955 LIQ
    92015 LIQS
  1000835 LIQ
             (LIQ OR LIQS)
  1384151 LIQUID
             (LIQUID OR LIQ)
  1171264 CRYSTAL
   617496 CRYSTALS
  1444992 CRYSTAL
             (CRYSTAL OR CRYSTALS)
     2529 (POLYMER (4A) DISPERS?) (5A) (LC OR LCD OR (LIQUID (4A) CRYSTAL))
```

2603 (PDLC OR ((POLYMER(4A)DISPERS?)(5A)(LC OR LCD OR (LIQUID(4A)CRYS

TAL))))

```
=> s (copy? or copied or master? or (contact(5a)expos?)) and l1
        60812 COPY?
         2863 COPIED
        29897 MASTER?
       445801 CONTACT
       108018 CONTACTS
       501678 CONTACT
                (CONTACT OR CONTACTS)
       761304 EXPOS?
         6694 CONTACT (5A) EXPOS?
            5 (COPY? OR COPIED OR MASTER? OR (CONTACT(5A)EXPOS?)) AND L1
L2
=> s (copy? or copied or master? or duplicat? or (contact(5a)expos?)) and l1
        60812 COPY?
         2863 COPIED
        29897 MASTER?
        32531 DUPLICAT?
       445801 CONTACT
       108018 CONTACTS
       501678 CONTACT
                (CONTACT OR CONTACTS)
       761304 EXPOS?
         6694 CONTACT (5A) EXPOS?
            5 (COPY? OR COPIED OR MASTER? OR DUPLICAT? OR (CONTACT(5A)EXPOS?))
L3
=> d all 1-5
L3
    ANSWER 1 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
    2004:360257 CAPLUS
DN
    140:383146
ED
    Entered STN: 04 May 2004
ΤI
    System and method for replicating volume holograms
    Sutherland, Richard L.; Sappington, John; Brandelik, Donna M.; Siwecki,
    Stephen A.; Shepherd, Christina K.; Pogue, Robert T.
    Science Applications International Corporation, USA
PA
    U.S., 29 pp.
    CODEN: USXXAM
DT
    Patent
    English
LA
     ICM G03H001-02
IC
INCL 430001000; 430002000; 359012000; 359003000
     74-8 (Radiation Chemistry, Photochemistry, and Photographic and Other
    Reprographic Processes)
FAN.CNT 1
                                        APPLICATION NO.
    PATENT NO.
                       KIND
                              DATE
                                                               DATE
                       _---
     -----
                              -----
                                         ______
                                                               _____
    US 6730442
                       B1
                              20040504 US 2000-577166
                                                               20000524
    US 2004175627
                       A1
                              20040909
                                         US 2004-796071
PRAI US 2000-577166
                       A1
                              20000524
CLASS
                CLASS PATENT FAMILY CLASSIFICATION CODES
 PATENT NO.
                ICM
                       G03H001-02
 US 6730442
                INCL
                       430001000; 430002000; 359012000; 359003000
 US 6730442
                NCL
                       430/001.000; 359/003.000; 359/012.000; 430/002.000
                ECLA
                       G02F001/1334H; G03H001/04F; G03H001/20; G03H001/28
 US 2004175627
                NCL
                       430/001.000
                      G02F001/1334H; G03H001/04F; G03H001/20; G03H001/28
                ECLA
AB
     The present invention offers increased efficiency and quality in the
       ***duplication*** of a ***master*** hologram utilizing an improved
     method of contact printing. This improved method of contact printing
                ***polymer*** - ***dispersed***
                                                   ***liq***
       ***crystal*** ( ***PDLC*** ) recording medium as the
       ***duplication***
                        blank and/or the ***master*** hologram material.
     The optical qualities of the ***PDLC*** material described herein
     provide an improved method of ***duplication*** using single beam
     contact printing regardless of the material comprising the
     hologram. Thus, ***master*** holograms originally recorded using
    highly complex optical geometries (e.g., computer generated holograms) are
                 ***duplication*** without the need for multiple beam
     capable of
```

power/intensity balancing and long recording times. The improved hologram contact printing method described herein works with virtually any type of ***master*** hologram, including both reflection and transmission holograms. replicating vol holograms Holography ***Polymer*** - ***dispersed*** ***liquid*** ***crystals*** (system and method for replicating vol. holograms) THERE ARE 136 CITED REFERENCES AVAILABLE FOR THIS RECORD RE.CNT 136 (1) Akashi; US 5354498 A 1994 CAPLUS (2) Amako; US 5682214 A 1997 CAPLUS (3) Anderson; US 5136666 A 1992 (4) Ando; US 5330264 A 1994 (5) Ando; US 5648857 A 1997 (6) Anon; EP 0087281 a 1983 (7) Anon; JP 60189729 A 1985 (8) Anon; JP 01-068784 a 1989 (9) Anon; JP 03-188479 a 1991 (10) Anon; WO 9727519 1997 CAPLUS (11) Anon; EP 0856765 A1 1998 CAPLUS (12) Anon; EP 0856766 A2 1998 CAPLUS (13) Anon; EP 0856768 A2 1998 CAPLUS (14) Anon; EP 0867749 A2 1998 (15) Anon; JP 10319237 1998 CAPLUS (16) Anon; WO 9804650 a 1998 CAPLUS (17) Anon; WO 9909440 1999 (18) Avant; US 5047039 A 1991 (19) Barak; US 4930674 A 1990 (20) Baues; US 4003629 A 1977 (21) Baues; US 4006963 A 1977 (22) Benton, S; SPIE 1979, V212, P2 (23) Benton, S; SPIE 1980, V215, P156 (24) Bischel; US 5544268 A 1996 (25) Bjelkhagen; US 5014709 A 1991 (26) Bjelkhagen, H; Applied Optics 1992, V31(8), P1041 (27) Bowley, C; Mol Cryst Liq 1999, V331, P209 (28) Brandstetter; US 5547786 A 1996 (29) Brumm; US 3758186 A 1973 (30) Buchkremer; US 5734485 A 1998 (31) Chang; US 4818045 A 1989 (32) Coates; US 5323251 A 1994 CAPLUS (33) Crawford; US 5875012 A 1999 CAPLUS (34) Crawford, G; SID International Symposium Digest of Applications Papers 1996, P99 (35) Crockard; US 5174276 A 1992 (36) Cushman; US 4983176 A 1991 (37) Damask; US 5915051 A 1999 (38) Deacon; US 5488681 A 1996 (39) Dejule; US 5363228 A 1994 (40) Dickson; US 5272550 A 1993 (41) Doane; US 4688900 A 1987 (42) Doane; US 5240636 A 1993 CAPLUS (43) Doane; US 5384067 A 1995 CAPLUS (44) Doane; US 5695682 A 1997 CAPLUS (45) Domash; US 5937115 A 1999 (46) Doyle; US 5003386 A 1991 (47) Faris; US 5680233 A 1997 CAPLUS (48) Fergason; US 4810063 A 1989 (49) Fergason; US 4856876 A 1989 (50) Gambogi; US 5930011 A 1999 CAPLUS (51) Goosen; US 4018228 A 1977 (52) Grayzel; US 4809713 A 1989 (53) Gunjima; US 4818070 A 1989 (54) Haines; US 4832445 A 1989 (55) Hall; US 5471326 A 1995 (56) Haugh; US 3658526 A 1972 CAPLUS (57) Healey; US 4923269 A 1990 (58) Heynderickx; US 5210630 A 1993 (59) Hirai; US 5235445 A 1993 CAPLUS

(60) Ingwall; US 5198912 A 1993 CAPLUS

(61) Jenkins; US 5661577 A 1997

ST

IT

RE

```
(62) Jubb; US 5356557 A 1994 CAPLUS
(63) Jubb; US 5698134 A 1997 CAPLUS
(64) Kaster; US 4368736 A 1983
(65) Kaster; US 5234447 A 1993
(66) Kaster; US 5366462 A 1994
(67) Kato; US 5852504 A 1998
(68) Keys; US 4942102 A 1990 CAPLUS
(69) Kirsch; US 4929240 A 1990
(70) Kuhl; US 4124947 A 1978
(71) Leib; US 5227859 A 1993
(72) Leith; US 3580655 A 1971
(73) Lougnot, D; Pure Appl Opt 1993, V2, P383 CAPLUS
(74) Madden; US 5170925 A 1992
(75) Margerum; US 3694218 A 1972 CAPLUS
(76) Margerum; US 4938568 A 1990 CAPLUS
(77) Margerum; US 5096282 A 1992 CAPLUS
(78) Martin; US 5725970 A 1998
(79) McGrew; US 4832424 A 1989
(80) Metz; US 5166813 A 1992
(81) Mihailov; US 5706375 A 1998
(82) Mikhailov, V; SPIE 1997, V3011, P200 CAPLUS
(83) Miller; US 4891152 A 1990 CAPLUS
(84) Nakao; US 5015249 A 1991
(85) Narancic; US 4374371 A 1983
(86) Nerad; US 5593615 A 1997 CAPLUS
(87) Nerad; US 5641426 A 1997 CAPLUS
(88) Newswanger; US 5291317 A 1994
(89) Nicholson; US 4416540 A 1983
(90) Nishiwaki; US 4560249 A 1985
(91) Nishiwaki; US 4673241 A 1987
(92) Oddsen; US 5220928 A 1993
(93) Ortiz; US 5376095 A 1994
(94) O'Callaghan; US 5182665 A 1993
(95) Perlin; US 4210132 A 1980
(96) Phillips; US 4857425 A 1989
(97) Pollack; US 4045124 A 1977
(98) Popovich; US 6115152 A 2000 CAPLUS
(99) Popovich; US 6211976 B1 2001 CAPLUS
(100) Redfield; US 5529861 A 1996
(101) Reinhorn; US 6172778 B1 2001 CAPLUS
(102) Saburi; US 5313317 A 1994 CAPLUS
(103) Sansone; US 5084203 A 1992 CAPLUS
(104) Schellenberg; US 5105298 A 1992 CAPLUS
(105) Simpson; US 5047040 A 1991
(106) Siutherland; SPIE 1994, V2152, P303
(107) Stone; US 5771320 A 1998
(108) Stroke, G; Physics Letters 1966, V20(4), P368
(109) Sturdevant; US 3667946 A 1972 CAPLUS
(110) Suga; US 5453338 A 1995
(111) Sutherland; US 5698343 A 1997
(112) Sutherland; US 5942157 A 1999 CAPLUS
(113) Sutherland; SPIE 1995, V2404, P132 CAPLUS
(114) Sutherland, R; Chem Mater 1993, V5, P1533 CAPLUS
(115) Taketomi; US 5731853 A 1998 CAPLUS
(116) Tanaka; US 5748272 A 1998 CAPLUS
(117) Tanaka; US 5751452 A 1998 CAPLUS
(118) Tokuda, A; Applied Optics 1980, V19(13), P2219
(119) Tokumitsu; US 5227906 A 1993
(120) Tondiglia; Opt Lett 1995, V20(11), P1325 CAPLUS
(121) Tzakis; US 5188638 A 1993
(122) Vaz; US 4728547 A 1988 CAPLUS
(123) Von Bally, G; Applied Optics 1984, V23(11), P1725
(124) Wang; US 5270843 A 1993 CAPLUS
(125) Weitzel, K; Optics Letters 1997, V22(24)
(126) West; US 5264950 A 1993
(127) Wilk; US 5258008 A 1993
(128) Wilk; US 5330486 A 1994
(129) Winston; US 5303322 A 1994
(130) Wreede; US 5499118 A 1996
(131) Wu; US 5661533 A 1997 CAPLUS
(132) Yamagishi; US 5011624 A 1991 CAPLUS
```

(133) Yariv; US 5832148 A 1998

```
(134) Yokoya; US 5328800 A 1994 CAPLUS
(135) Zhang, J; J Am Chem Soc 1992, V114(4), P1506 CAPLUS
(136) Zhang, J; SPIE 1994, V2042, P238 CAPLUS
L3
     ANSWER 2 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
AN
     1998:483253 CAPLUS
     129:189970
DN
     Entered STN: 04 Aug 1998
ED
TI
     Effect of molar mass of an epoxy oligomer on the phase separation in epoxy
             ***polymer***
                             ***dispersed***
                                                   ***liquid***
       ***crystals***
     Siddiqi, Humaira Masood; Dumon, Michel; Pascault, Jean Pierre
ΑU
     Laboratoire des Mat riaux Macromoleculaires UMR 5627 CNRS, Institut
CS
     National des Sciences Appliquees, Villeurbanne, F- 69 621, Fr.
     Journal of Materials Chemistry (1998), 8(8), 1691-1695
SO
     CODEN: JMACEP; ISSN: 0959-9428
PR
     Royal Society of Chemistry
DT
     Journal
     English
LA
CC
     37-5 (Plastics Manufacture and Processing)
     Section cross-reference(s): 75
       ***Polymer***
AB
                         ***dispersed***
                                             ***liq***
                                                        . ***crystals***
     based on epoxy-amine [DGEBA-Jeffamine D400] crosslinked matrixes and a
     nematic liq. crystal, E7, were studied over the course of polymn., i.e. as
     a function of the polymn. conversion. The effect of the mol. wt. of the
     epoxy oligomer on the initial temp.-concn. and the temp.-conversion phase
     diagrams was studied. An increase of the epoxy oligomer mol. wt. greatly
     reduces the initial liq. crystal soly. and brings the cloud point to
     earlier polymn. conversions, which were quantified. Thus the phase sepn.
     is markedly enhanced. The temp.-conversion phase diagrams were
     characterized at two isothermal polymn. temps. for one liq. crystal compn.
     (50 wt.). These diagrams (isotropic-nematic and nematic-isotropic
     transition temps.) obey
                               ***master***
                                             curves when the mol. wt. of the
     epoxy is varied. The size of the liq. crystal droplets decreases when the
    mol. wt. of the epoxy increases. This effect is mainly due to the
    viscosity increase resulting from the oligomer wt. increase. Viscosity
     measurements were made at intervals during polymn.
ST
     epoxy oligomer E7 liq crystal phase; phase sepn liq crystal epoxy
ΙT
     Cloud point
     Phase diagram
     Phase separation
     Viscosity
        (effect of mol. wt. of epoxy oligomer on phase sepn. of epoxy/E7 liq.
        crystal dispersion)
IT
     Epoxy resins, preparation
     RL: PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)
        (effect of mol. wt. of epoxy oligomer on phase sepn. of epoxy/E7 liq.
        crystal dispersion)
IT
     Liquid crystals
        (nematic; effect of mol. wt. of epoxy oligomer on phase sepn. of
        epoxy/E7 liq. crystal dispersion)
IT
     Liquid crystals
        (transitions, nematic-isotropic transition; effect of mol. wt. of epoxy
        oligomer on phase sepn. of epoxy/E7 liq. crystal dispersion)
IT
     63748-28-7, E7
     RL: PRP (Properties)
        (effect of mol. wt. of epoxy oligomer on phase sepn. of epoxy/E7 liq.
        crystal dispersion)
     110302-44-8P, DGEBA-Jeffamine D400 copolymer
     RL: PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)
        (effect of mol. wt. of epoxy oligomer on phase sepn. of epoxy/E7 liq.
        crystal dispersion)
RE.CNT
              THERE ARE 17 CITED REFERENCES AVAILABLE FOR THIS RECORD
       17
RE
(1) Aklonis, J; Introduction to polymer viscoelasticity 1982
(2) Borrajo, J; Polymer 1998, V39, P845 CAPLUS
(3) Dusek, K; J Polym Sci, Polym Symp 1975, V53, P29 CAPLUS
(4) Eloundou, J; Macromolecules 1996, V29, P6907 CAPLUS
(5) Eloundou, J; Macromolecules 1996, V29, P6917 CAPLUS
(6) Fox, T; Bull Am Chem Soc 1956, V2, P123
(7) Hirai, Y; SPIE 1990, V1257, P2 CAPLUS
(8) Kim, B; J Polym Sci, Part B: Polym Phys 1995, V33, P707 CAPLUS
```

```
(9) Kyu, T; Mol Cryst Liq Cryst 1996, V287, P27 CAPLUS
(10) Macosko, C; Macromolecules 1976, V9, P199 CAPLUS
(11) Masood, H; Polymer 1996, V37, P4795
(12) Montarnal, S; Ph D Thesis, INSA de Lyon 1987, P190
(13) Ono, H; Polym Bull 1995, V35, P364
(14) Siddiqi, H; Mol Cryst Liq Cryst, in the press 1998
(15) Utracki, L; Polymer Alloys and Blends 1990
(16) West, J; Mol Cryst Liq Cryst 1988, V157, P427 CAPLUS
(17) Williams, R; Adv Polym Sci 1997, V128, P95 CAPLUS
    ANSWER 3 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
L3
AN
    1997:655031 CAPLUS
    127:353053
DN
    Entered STN: 15 Oct 1997
ED
TI
    Liquid crystal display
IN
     Ikeda, Mitsushi; Fukunaga, Yoko
PA
    Toshiba Corp., Japan
SO
    Jpn. Kokai Tokkyo Koho, 16 pp.
    CODEN: JKXXAF
DT
    Patent
LA
    Japanese
IC
    ICM G02F001-136
    ICS G02F001-1333; G02F001-1343
CC
    74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other
    Reprographic Processes)
FAN.CNT 1
    PATENT NO.
                        KIND
                               DATE
                                           APPLICATION NO.
                                                                 DATE
                               -----
     ------
                        ----
                                           _____
                                                                  -----
     JP 09258260
                         A2
                               19971003
                                           JP 1996-66634
                                                                 19960322
PΙ
PRAI JP 1996-66634
                               19960322
CLASS
                CLASS PATENT FAMILY CLASSIFICATION CODES
 PATENT NO.
 _____
                ----
                       _____
JP 09258260
                TCM
                       G02F001-136
                ICS
                       G02F001-1333; G02F001-1343
    The title display has contact holes for connecting TFTs and pixel
AB
    electrodes, and an insulation film covered on the exposure regions of the
    pixel electrodes and common electrodes. The liq. crystal display may have
                                         ***crystal*** / ***polymer***
     multiple dye-contg. ***liq*** .
                         layers. The invention can assure good connection and
       ***dispersion***
     offer a simple way for manuf. of the high quality liq. crystal display.
ST
     liq crystal display contact hole; insulation film liq crystal display
IT
    Acrylic polymers, uses
    RL: DEV (Device component use); TEM (Technical or engineered material
     use); USES (Uses)
        (forming insulation film in
                                     ***contact***
                                                     holes for covering
          ***exposure***
                         region of pixel and common electrode for liq. crystal
       display)
IT
    Liquid crystal displays
        (having contact hole for connecting TFTs and pixel electrodes)
IT
     1518-16-7, Tetra cyano quinodimethane
                                            7440-02-0, Nickel, uses
     25233-30-1, Polyaniline 30604-81-0, Polypyrrole
    RL: DEV (Device component use); TEM (Technical or engineered material
    use); USES (Uses)
        (coated on contact hole for connecting TFT and pixel electrode)
    ANSWER 4 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
L3
     1994:521852 CAPLUS
AN
DN
     121:121852
ED
    Entered STN: 03 Sep 1994
ΤI
    Copier-platen liquid-crystal variable area-mask devices
IN
    Ueno, Osamu; Hiji, Naoki
PA
    Fuji Xerox Co Ltd, Japan
SO
    Jpn. Kokai Tokkyo Koho, 12 pp.
    CODEN: JKXXAF
DT
    Patent
LA
    Japanese
IC
     ICM G02F001-1333
     ICS G02F001-13; G02F001-1343; G03B027-62; G03G015-00; H04N001-04
ICA
    G03G015-04
CC
    74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other
    Reprographic Processes)
```

```
Section cross-reference(s): 73
FAN.CNT 1
                   KIND DATE APPLICATION NO. DATE
    PATENT NO.
                      A2 19940225 JP 1993-135208 19930514
PI JP 06051295
PRAI JP 1992-166703
                      ____
                      A1 19920603
CLASS
 PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
               ----
 -----
 JP 06051295 ICM G02F001-1333
              ICS G02F001-13; G02F001-1343; G03B027-62; G03G015-00;
                      H04N001-04
               ICA G03G015-04
    The device comprises: a matrix array of electrooptical ***polymer*** - ***dispersed*** ***liq*** - ***crystal*** microcells; and means
AB
    for driving the individual microcells for forming various transparent
    patterns. The device is suited for use as a variable mask on the platen
    of a ***copying*** machine.
    lig crystal microcell array platen mask
ST
    Optical imaging devices
IT
        (electrooptical ***liq*** .- ***crystal*** , ***polymer*** -
         ***dispersed*** microcell array, in variable-area platen masks, for
       copiers)
IT
    25038-59-9, Polyethylene terephthalate, uses
    RL: USES (Uses)
       ( ***lig*** .- ***crystal*** ***polymer*** - ***dispersed***
       microcell arrays, as substrate)
L3
    ANSWER 5 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
AN
    1992:613850 CAPLUS
DN
    117:213850
    Entered STN: 28 Nov 1992
ED
    Composites of thermoplastic and liquid crystal polymers and their
ΤI
    manufacture
IN
    Coffey, Gerald P.; Perec, Elena S.; Melamud, Lucy
    BP America, Inc., USA
PΑ
    Eur. Pat. Appl., 24 pp.
SO
    CODEN: EPXXDW
DT
    Patent
    English
LA
IC
    ICM C08L101-00
    ICS C08L067-03
    37-6 (Plastics Manufacture and Processing)
CC
    Section cross-reference(s): 75
FAN.CNT 1
                   KIND DATE APPLICATION NO. DATE
    PATENT NO.
                       ----
    _____
                                         _____
    EP 499387 A2 19920819 EP 1992-300827
EP 499387 A3 19921223
                                                              19920131
PΙ
       R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, MC, NL, PT, SE
    CA 2060494 AA 19920814 CA 1992-2060494 19920131
CN 1067913 A 19930113 CN 1992-101629 19920212
                                        CN 1992-101629
CN 1067913 A 19930113 CN 1992-101629
JP 05214253 A2 19930824 JP 1992-26416
PRAI US 1991-654853 A 19910213
                                                              19920213
CLASS
 PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
 -----
 EP 499387 ICM C08L101-00 ICS C08L067-03
    Chem resistant and mech. strong composites contg. .ltoreq.2% ***liq***
AB
     . ***crystal*** ***polymer*** (LCP) ***dispersed*** in a
     thermoplastic resin are manufd. by dispersing .gtoreq.2% solid LCP into
    molten thermoplastic and dilg. the ***masterbatch*** with addnl.
     thermoplastic polymer. Moldings, prepd. from 90/10 high-d. polyethylene
     (HDPE)-Vectra A950 (I, liq.-cryst. polyester) ***masterbatch*** with
    subsequent diln. by HDPE to I content 1%, had tensile strength 3518.9 psi,
    yield elongation 11.19%, break elongation .gtoreq.995% (for 3 of 6
     samples), and good chem resistance.
ST
    polyethylene liq cryst polyester blend; chem resistance polyethylene
    polyester blend; dispersion liq cryst polyester polyethylene
IT
     Impact-resistant materials
        (blends of liq.-cryst. polyesters and thermoplastic polymers as, with
```

```
Acrylic polymers, uses
IT
    Polyamides, uses
     RL: USES (Uses)
        (liq.-cryst. polyester blends with, with good mech. strength and chem
        resistance)
     Plastics, molded
TT
     RL: USES (Uses)
        (liq.-cryst. polyester blends, with good mech. strength and chem
        resistance)
     Polyesters, miscellaneous
     RL: MSC (Miscellaneous)
        (liq.-cryst., blends with thermoplastic polymers, with good mech.
        strength and chem resistance)
     Alkenes, polymers
     RL: USES (Uses)
        (polymers, liq.-cryst. polyester blends with, with good mech. strength
        and chem resistance)
     Chemically resistant materials
        (solvent-resistant, blends of liq.-cryst. polyesters and thermoplastic
        polymers as, with good mech. strength)
     Liquid crystals, polymeric
        (thermotropic, polyester, blends with thermoplastic polymers, with good
        mech. strength and chem resistance)
                                              81843-52-9, Vectra A 950
     25822-54-2, Rodrun
                          31072-56-7, Xydar
IT
     RL: USES (Uses)
        (blends with thermoplastic polymers, with good mech. strength and chem
        resistance)
     9003-07-0, Polypropylene
     RL: USES (Uses)
        (liq.-cryst. polyester blends with 5C08, with good mech. strength and
        chem resistance)
     9002-88-4, Polyethylene
                               9003-53-6
                                           9010-79-1, Ethylene-propylene
     copolymer 25068-26-2, Poly(4-methyl-1-pentene)
                                                        26221-73-8, Dowlex 2045
     108771-80-8, Barex 210
     RL: USES (Uses)
        (lig.-cryst. polyester blends with, with good mech. strength and chem
        resistance)
=> d his
     (FILE 'HOME' ENTERED AT 15:39:55 ON 16 AUG 2005)
     FILE 'CAPLUS' ENTERED AT 15:40:03 ON 16 AUG 2005
           2603 S (PDLC OR ((POLYMER(4A)DISPERS?)(5A)(LC OR LCD OR (LIQUID(4A)C
L1
              5 S (COPY? OR COPIED OR MASTER? OR (CONTACT(5A)EXPOS?)) AND L1
L2
              5 S (COPY? OR COPIED OR MASTER? OR DUPLICAT? OR (CONTACT(5A) EXPOS
L3
=> log y
COST IN U.S. DOLLARS
                                                  SINCE FILE
                                                                  TOTAL
                                                       ENTRY
                                                                SESSION
                                                       51.12
                                                                  51.33
FULL ESTIMATED COST
DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS)
                                                  SINCE FILE
                                                                  TOTAL
                                                       ENTRY
                                                                SESSION
CA SUBSCRIBER PRICE
                                                       -3.65
                                                                  -3.65
```

good mech. strength and chem resistance)

STN INTERNATIONAL LOGOFF AT 15:43:06 ON 16 AUG 2005